



IXTK110N30 Information



For Reference Only

Part Number IXTK110N30

Manufacturer IXYS

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description MOSFET N-CH 300V 110A TO-264

Package TO-264-3, TO-264AA

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









IXTK110N30 Specifications

	IXTK110N30 IXYS
Manufacturer	IXYS
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Category	Discrete Semiconductor Products
,	Transistors - FETs, MOSFETs - Single
Package	TO-264-3, TO-264AA
Series	MegaMOS?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	300V
Current - Continuous Drain (Id) @ 25°C	110A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 250μA
Gate Charge (Qg) (Max) @ Vgs	390nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	7800pF @ 25V
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	730W (Tc)
Rds On (Max) @ Id, Vgs	26 mOhm @ 500mA, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-264 (IXTK)
Package / Case	TO-264-3, TO-264AA
	Report errors?

IXTK110N30 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

IXTK110N30 Payment Methods



















IXTK110N30 Shipping Methods













If you have any question about IXTK110N30, please do not hesitate to contact us!

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